



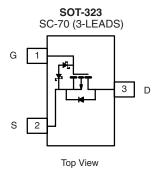
P-Channel 1.8 V (G-S) MOSFET

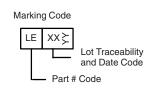
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
- 8	0.280 at V _{GS} = - 4.5 V	± 0.92		
	0.380 at V _{GS} = - 2.5 V	± 0.79		
	0.530 at V _{GS} = - 1.8 V	± 0.67		

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- ESD Protection: 3000 V
- Compliant to RoHS Directive 2002/95/EC







Ordering Information: Si1305EDL-T1-E3 (Lead (Pb)-free) Si1305EDL-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	S T _A = 25 °C, ur	nless otherw	ise noted		
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	- 8		V
Gate-Source Voltage		V _{GS}	± 8		
Continuous Dunin Commant /T 150 00\8	T _A = 25 °C	- I _D	± 0.92	± 0.86	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		± 0.74	± 0.69	
Pulsed Drain Current		I _{DM}	± 3		Α
Continuous Diode Current (Diode Conduction) ^a		I _S	- 0.28	- 0.24	1
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	0.34	0.29	W
	T _A = 70 °C		0.22	0.19	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 5 s	R _{thJA}	315	375	°C/W	
Maximum Junction-to-Ambient	Steady State		360	430		
Maximum Junction-to-Foot (Drain)	Steady State		285	340		

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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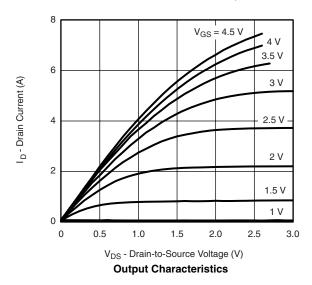
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	•			•			
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45			٧	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 6.4 V, V _{GS} = 0 V			- 1		
		V _{DS} = - 6.4 V, V _{GS} = 0 V, T _J = 70 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} - 5 V, V _{GS} = - 4.5 V	- 3			Α	
		V _{GS} = - 4.5 V, I _D = - 1 A		0.230	0.280	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 0.5 A		0.315	0.380		
		V _{GS} = - 1.8 V, I _D = - 0.3 A		0.440	0.530		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 1 A		3.5		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1 A, V _{GS} = 0 V			- 1.2	٧	
Dynamic ^b	•						
Total Gate Charge	Qg			2.6	4		
Gate-Source Charge	Q _{gs}	Q_{gs} $V_{DS} = -4 V$, $V_{GS} = -4.5 V$, $I_D = -1 A$		0.54		nC	
Gate-Drain Charge	Q_{gd}			0.52		1	
Turn-On Delay Time	t _{d(on)}			206	330		
Rise Time	t _r	$V_{DD} = -4 \text{ V}, R_{I} = 4 \Omega$		431	690	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -1 \text{ A, } V_{GEN} = -4.5 \text{ V, } R_g = 6 \Omega$		1350	2160		
Fall Time	t _f			1000	1600		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1 A, dI/dt = 100 A/μs		500	800		

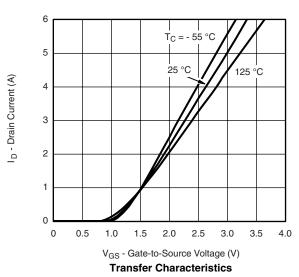
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



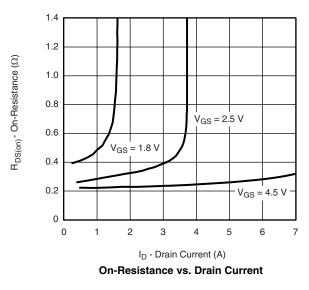


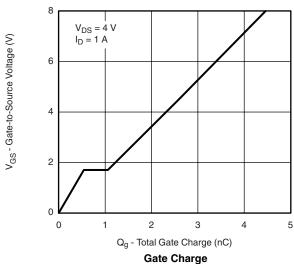


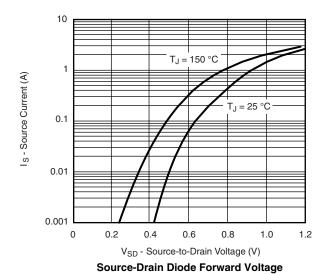


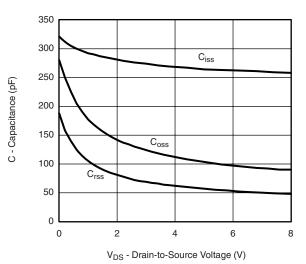


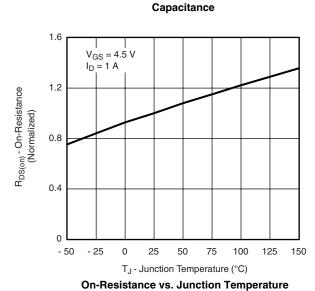
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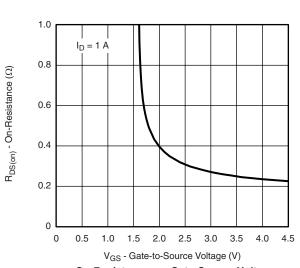










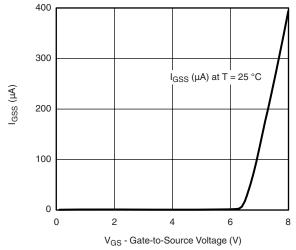


On-Resistance vs. Gate-Source Voltage

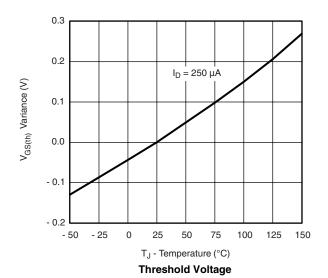
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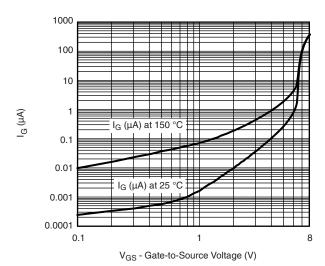
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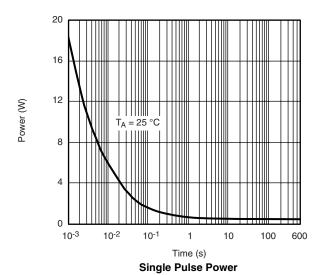






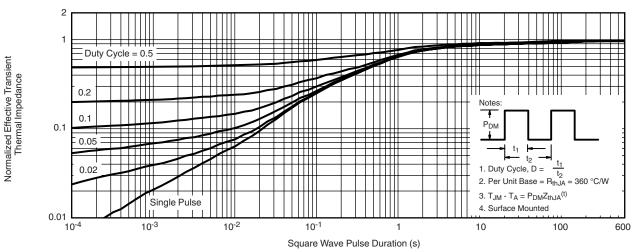


Gate-to-Source Voltage vs. Gate Current

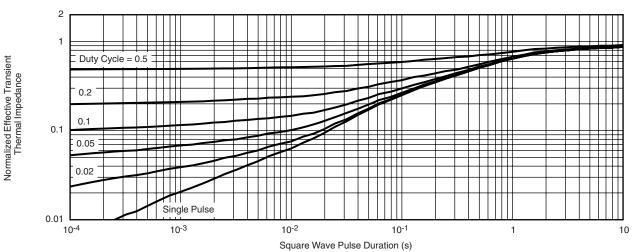




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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